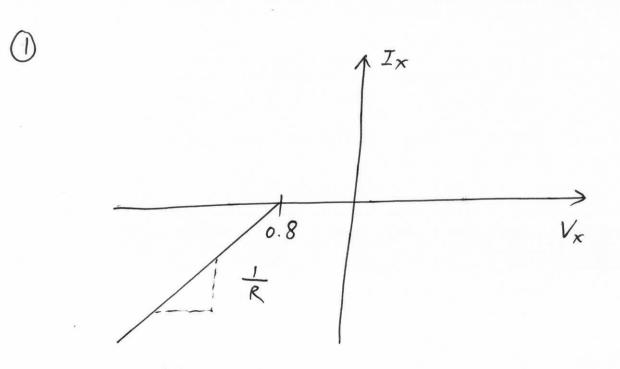
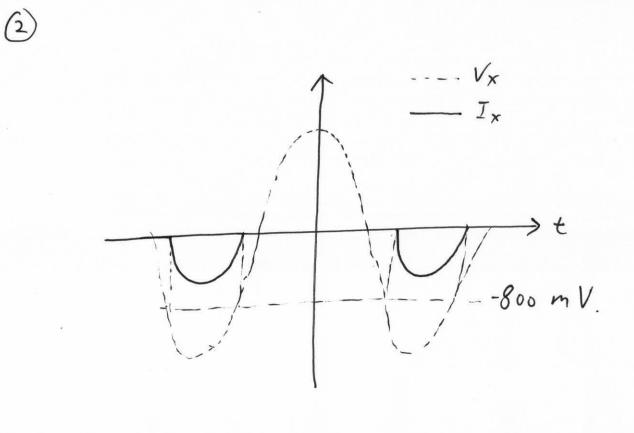
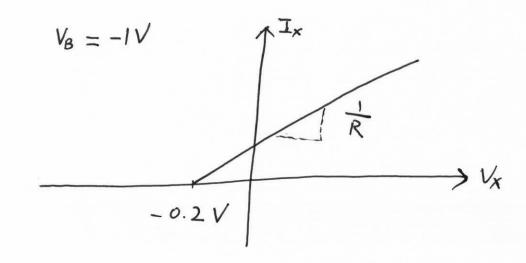
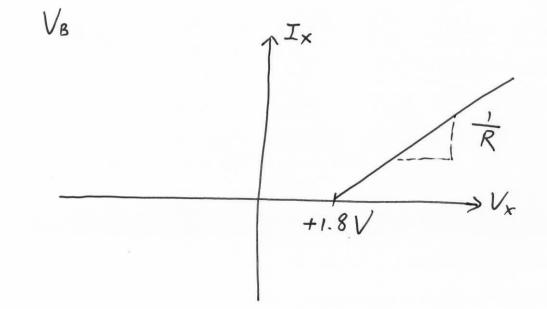
Fundamentals of Microelectronics 2nd Edition Razavi Solutions Manual

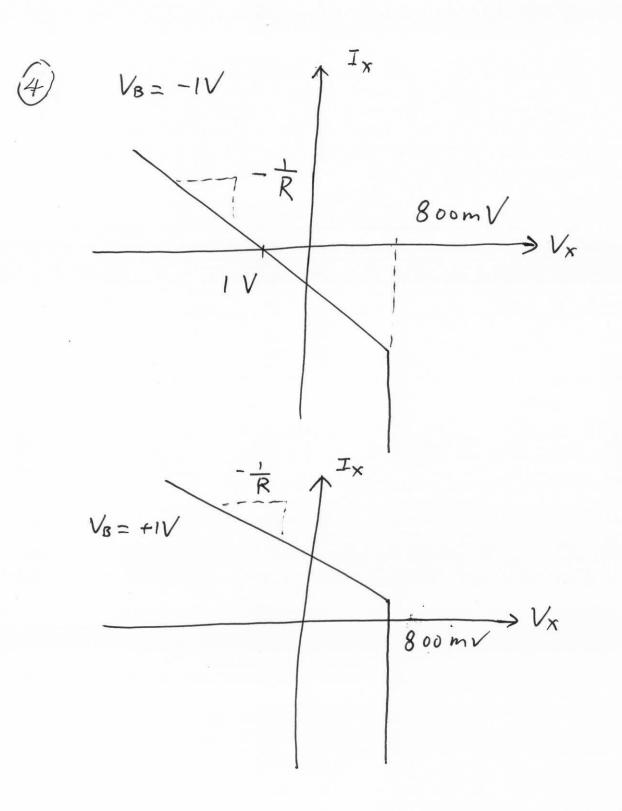
ch3

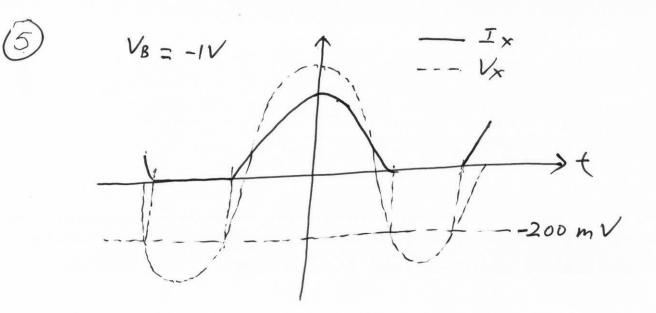


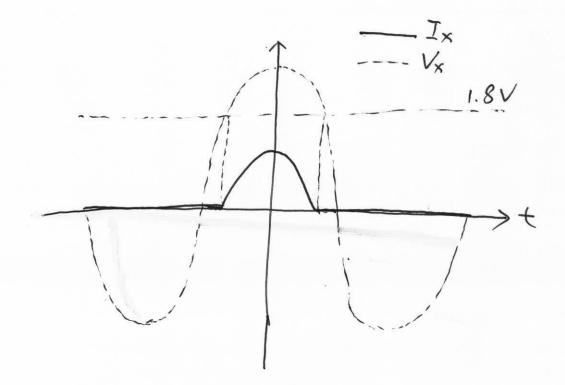


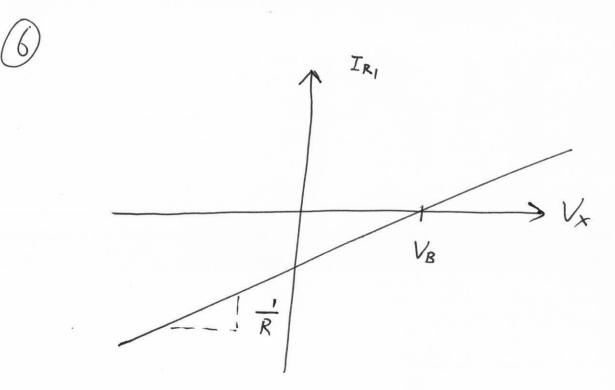




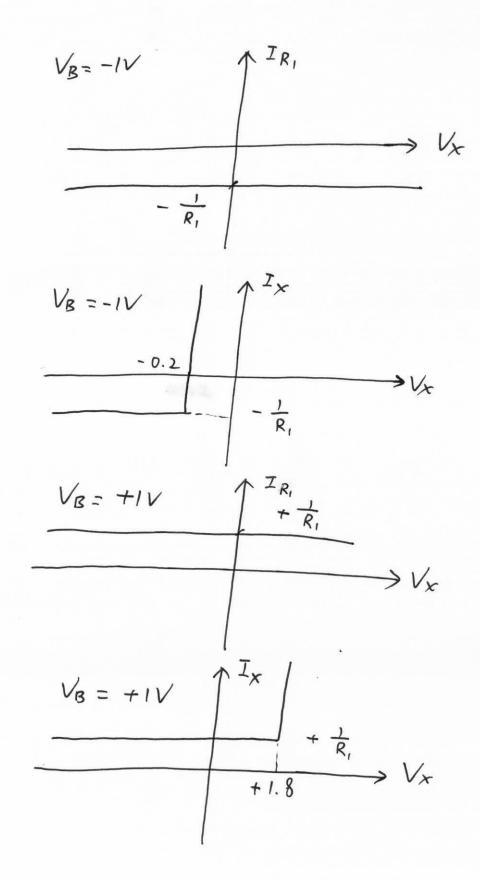






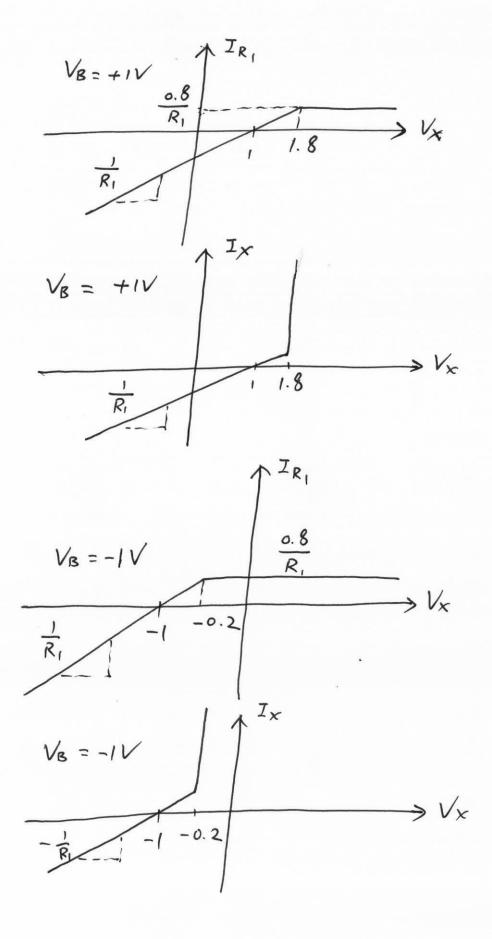


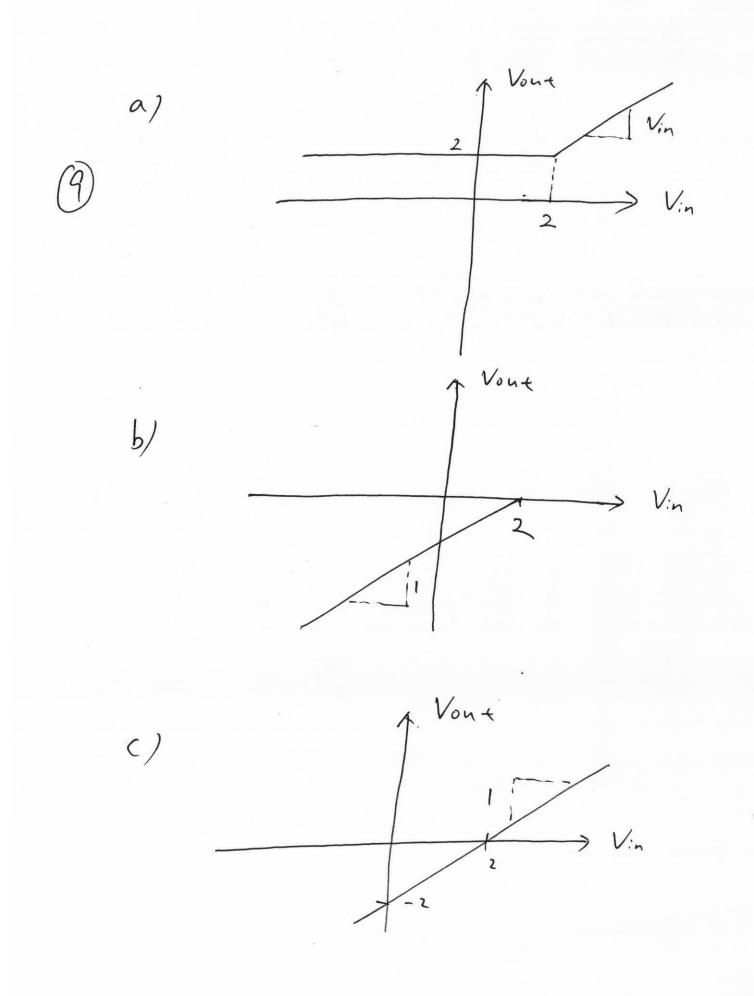
Ip, = 0 for all Vx (:: VB >0, D, is reverse - biased)

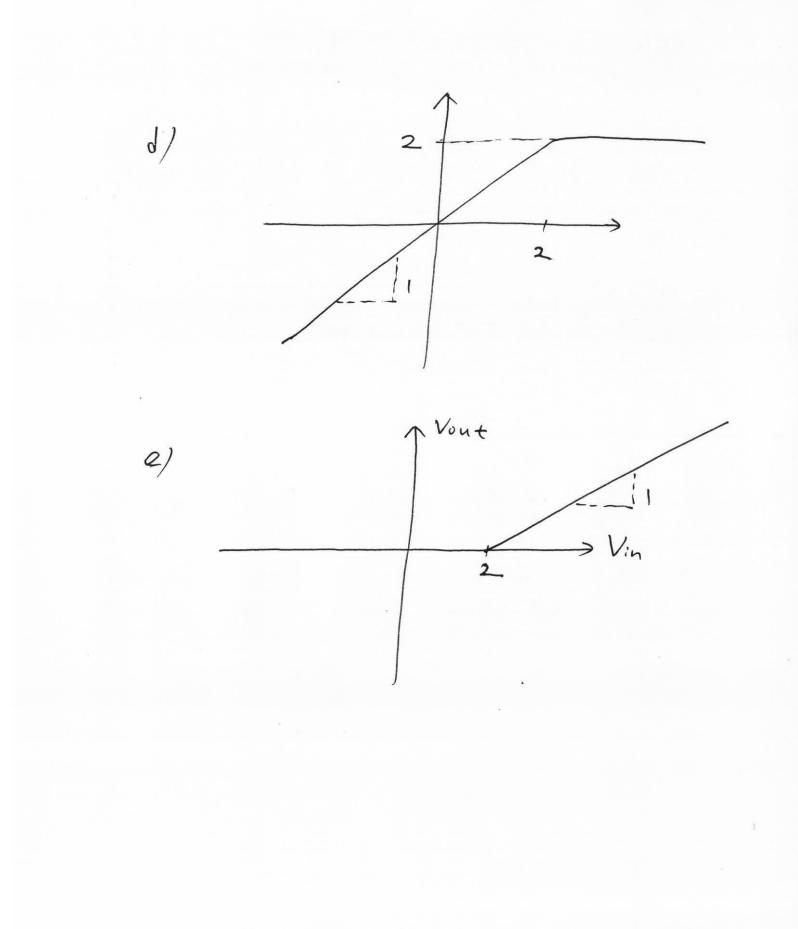


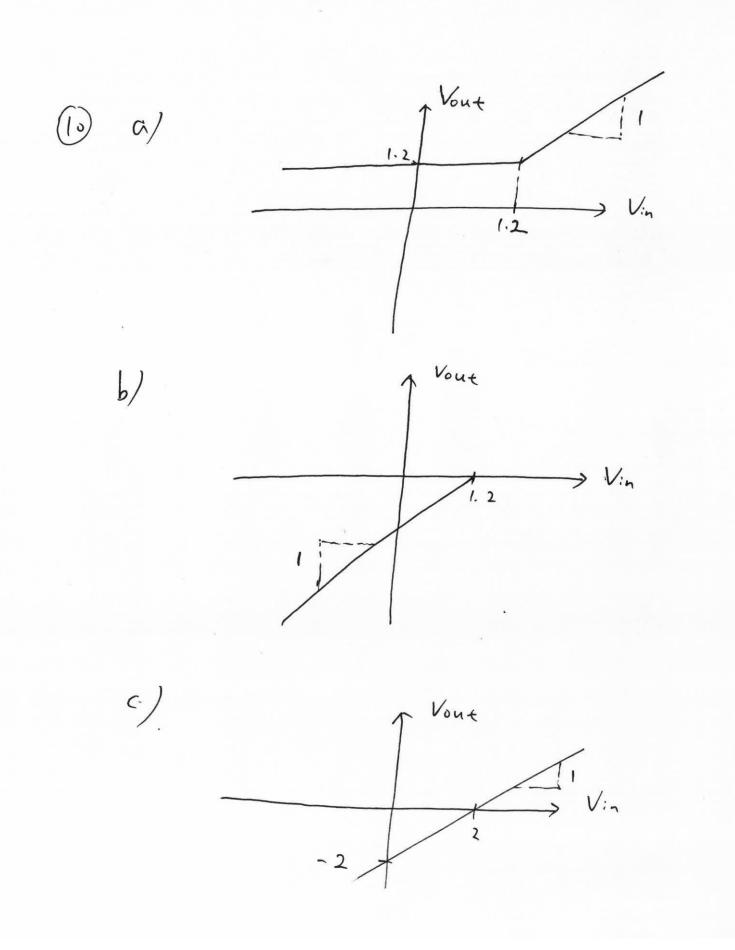
(F)

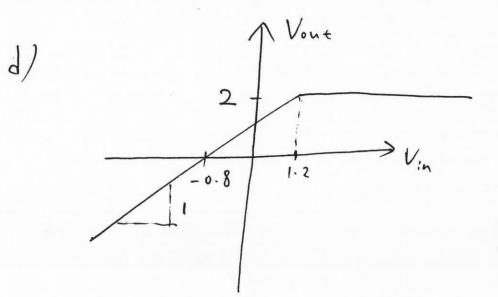
(8)

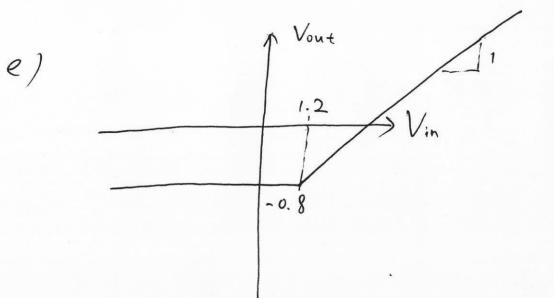


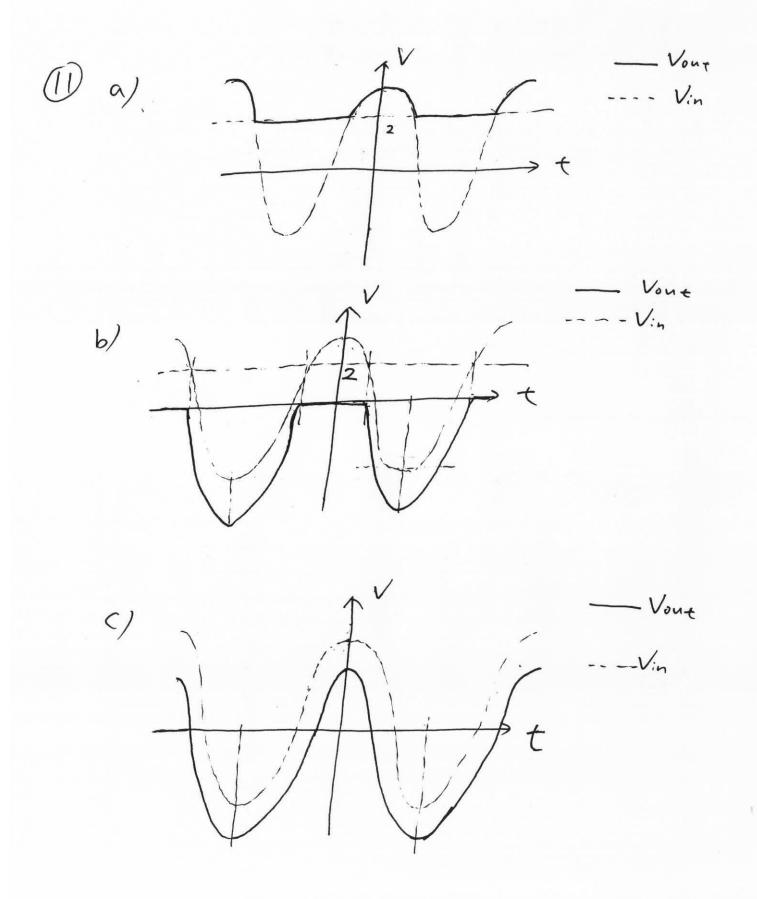


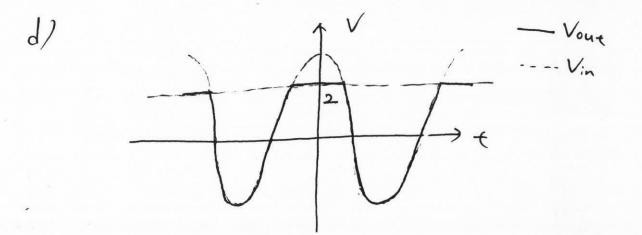


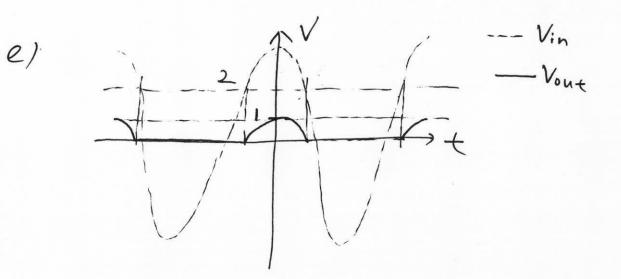


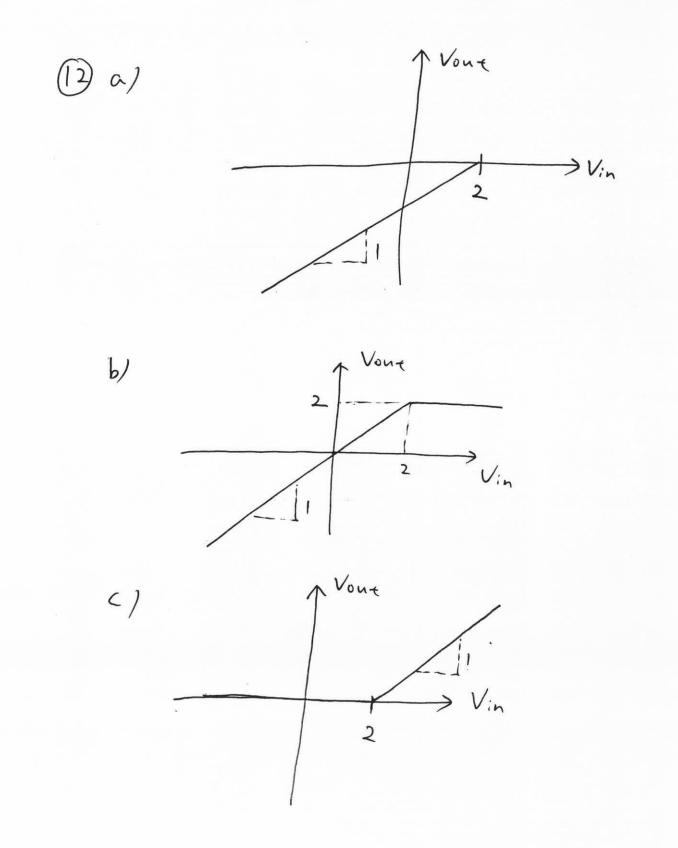


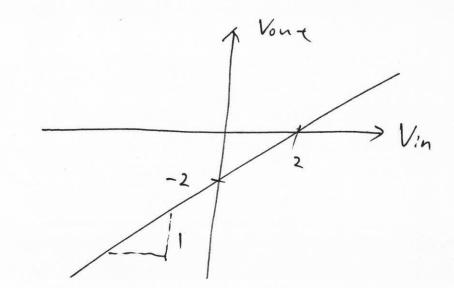


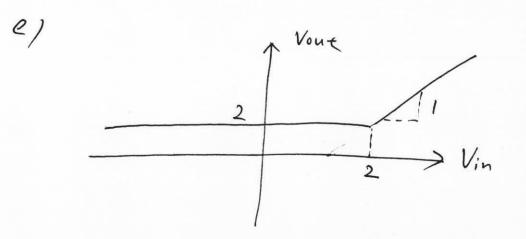






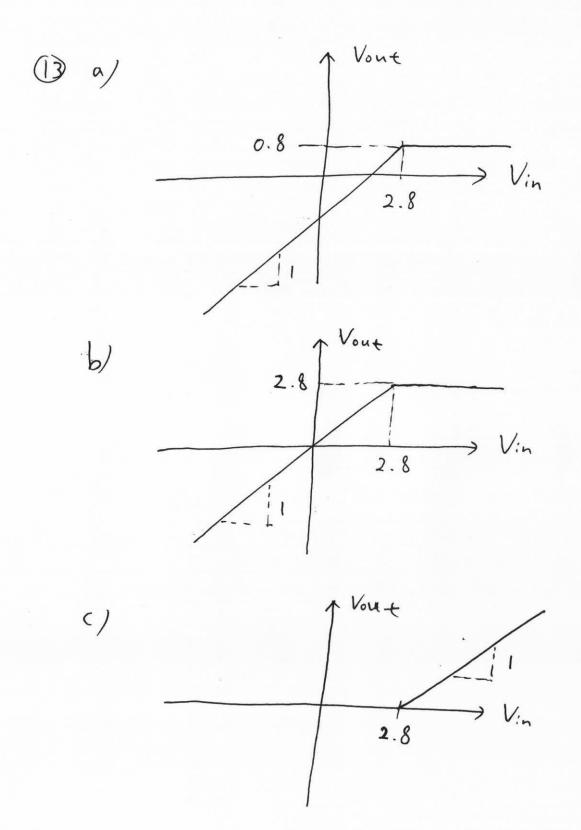


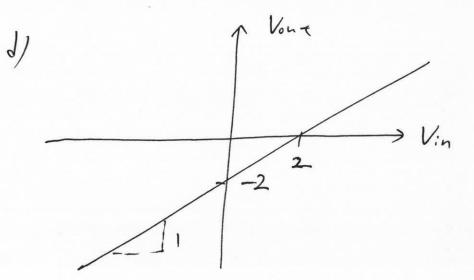


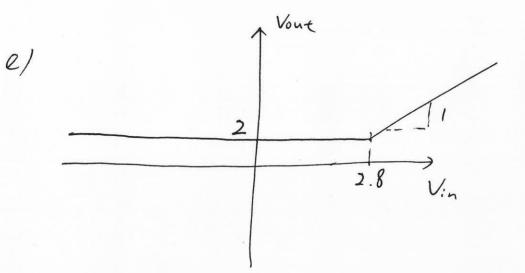


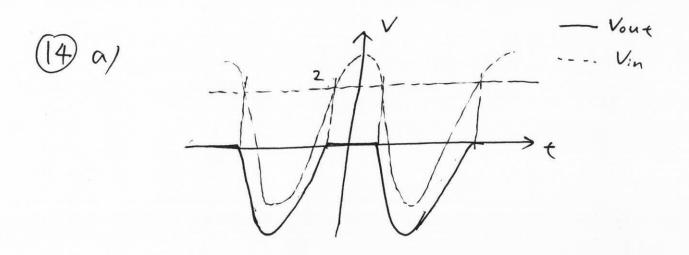
2)

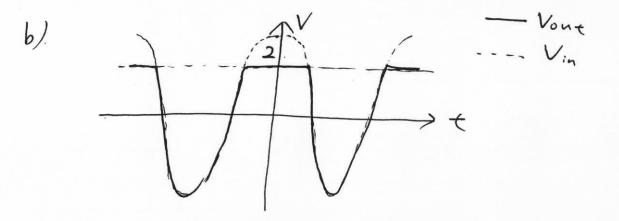
×

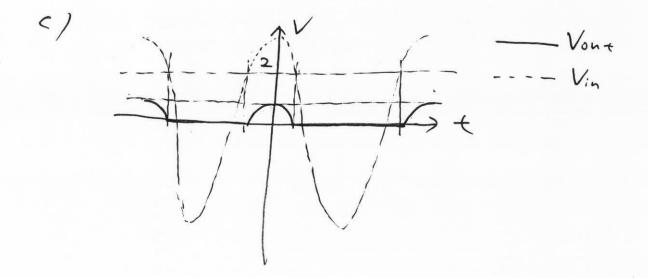


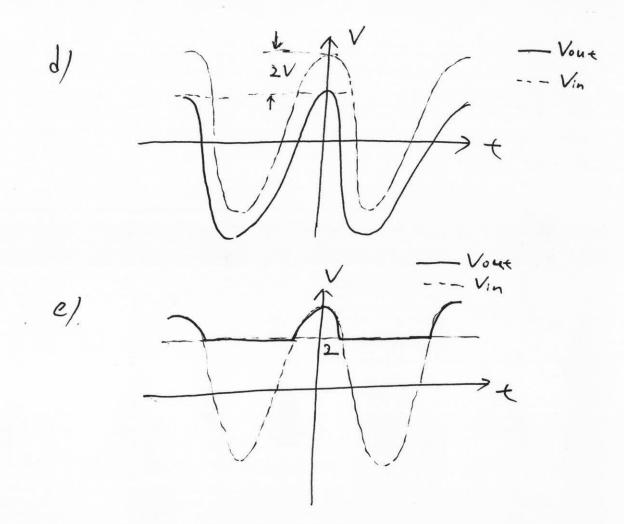


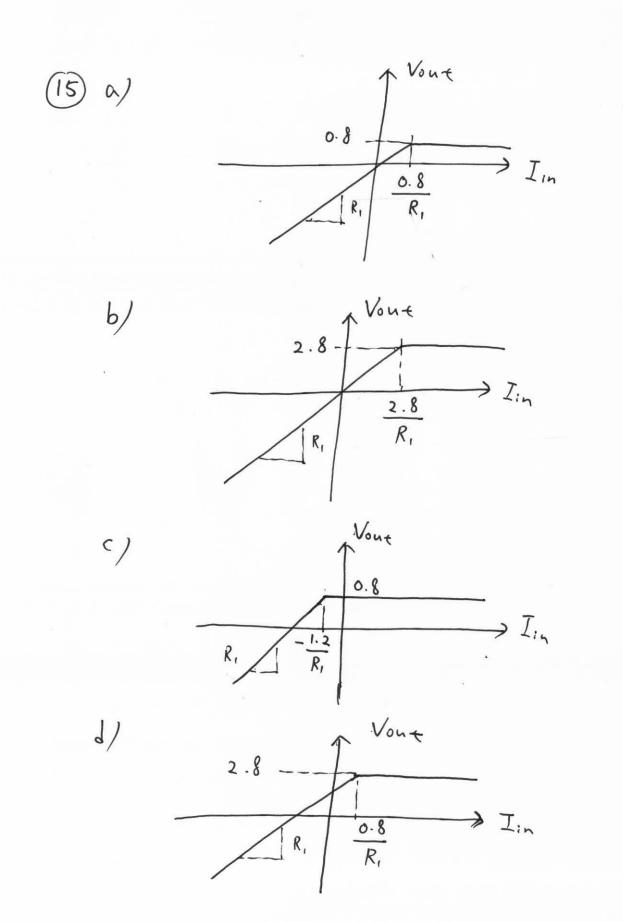


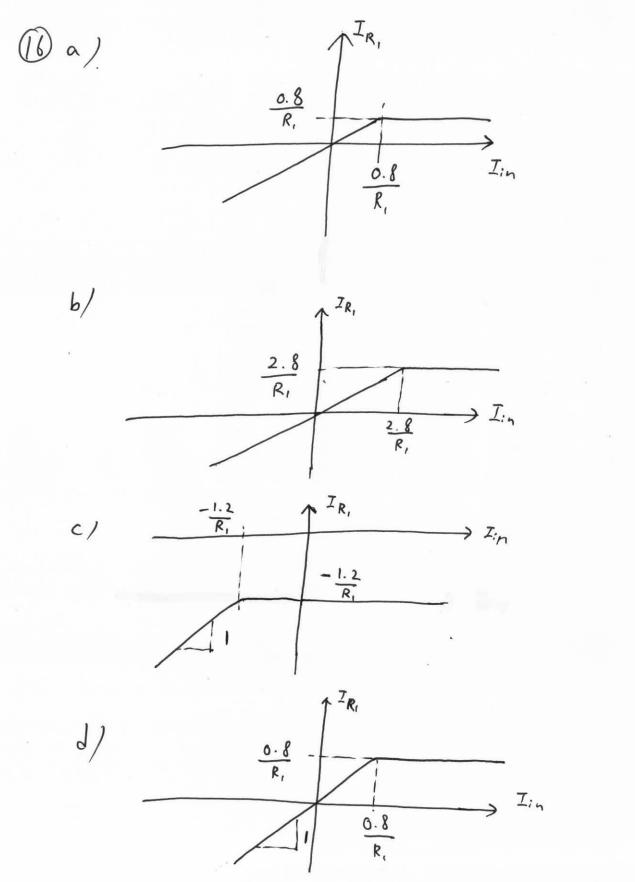


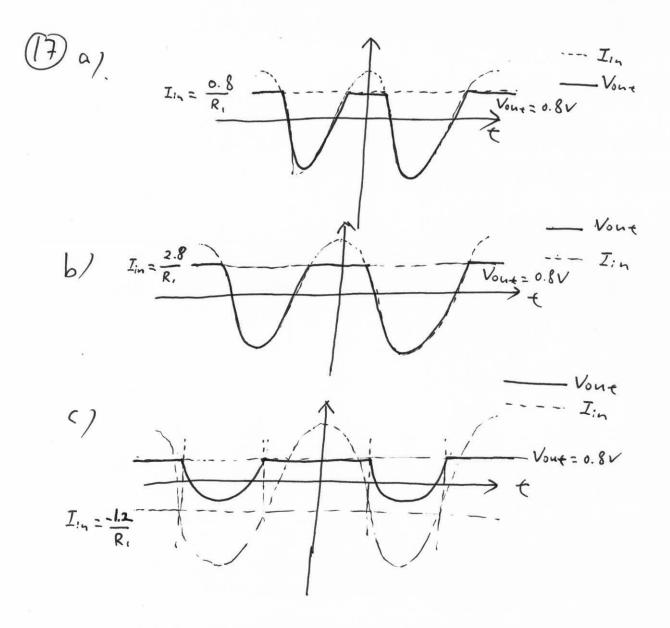


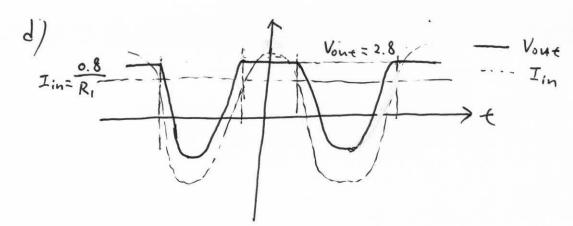










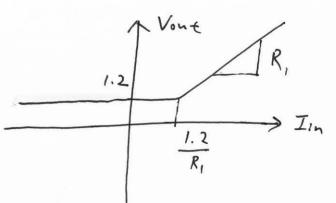


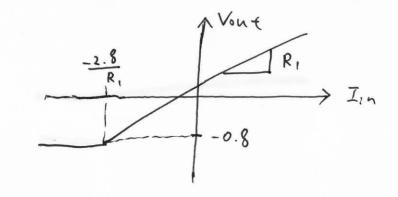


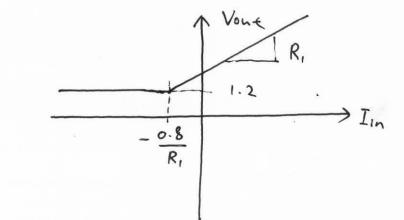


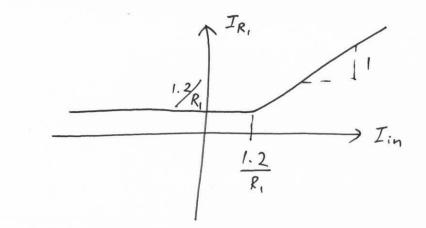
6/

c)



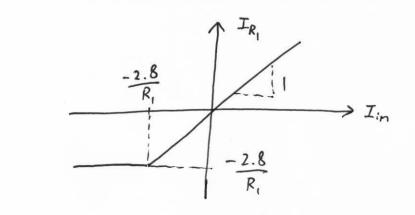


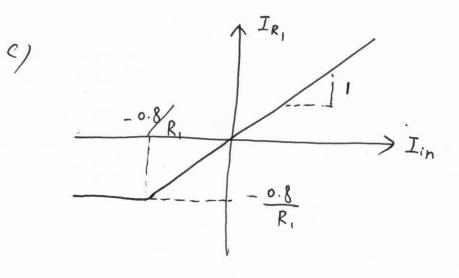


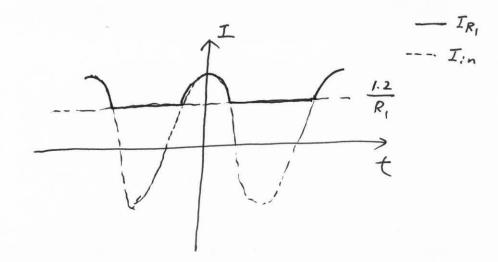


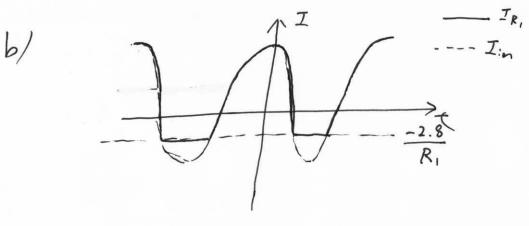
(19) a)

b)

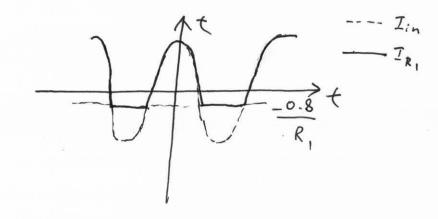


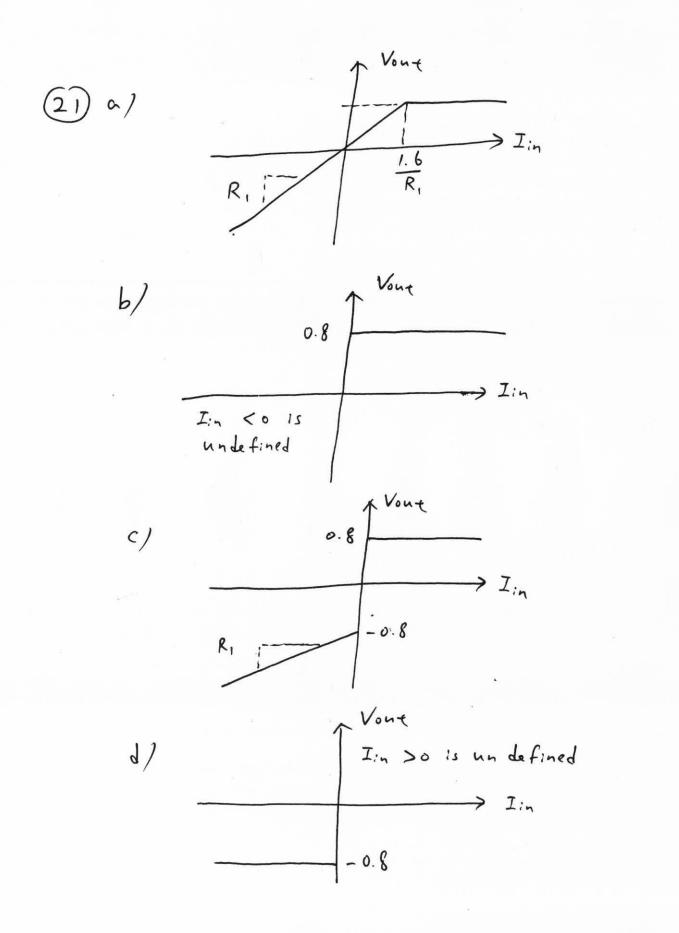


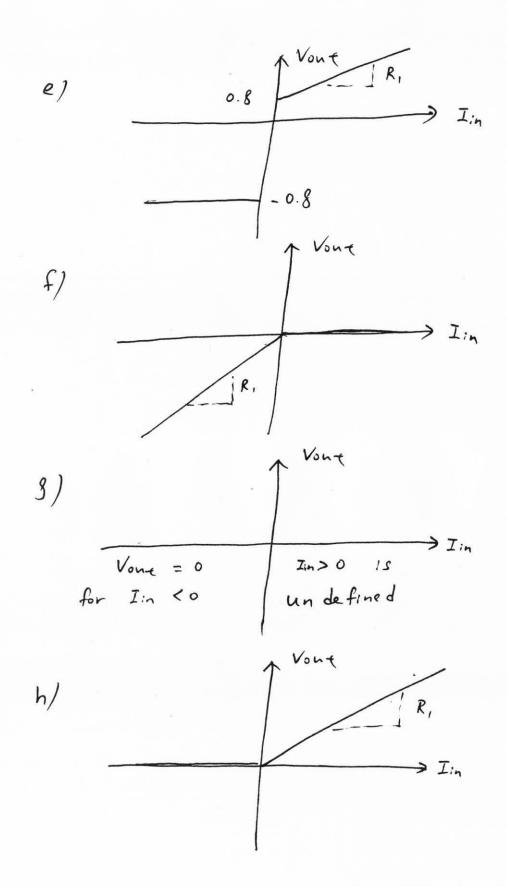


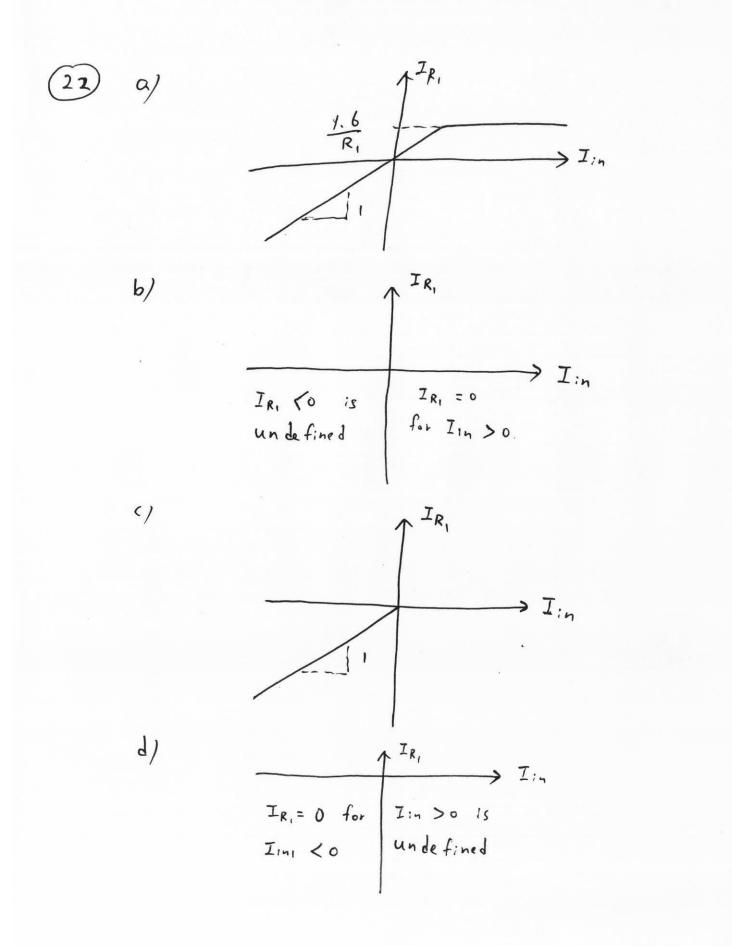


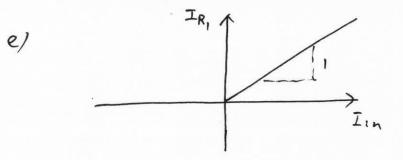


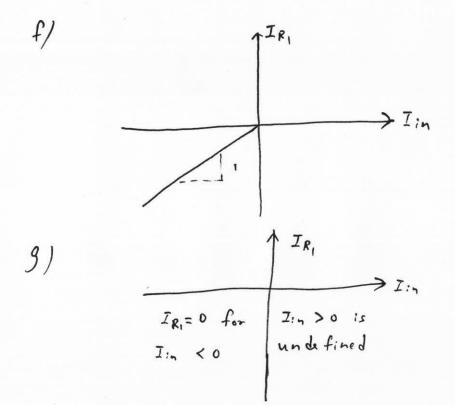


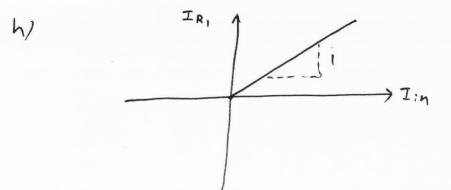


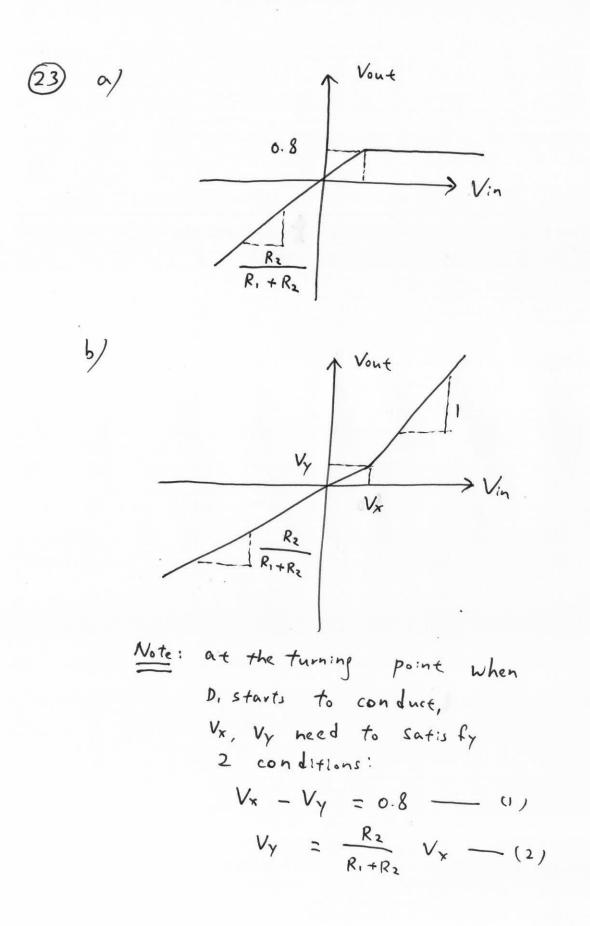


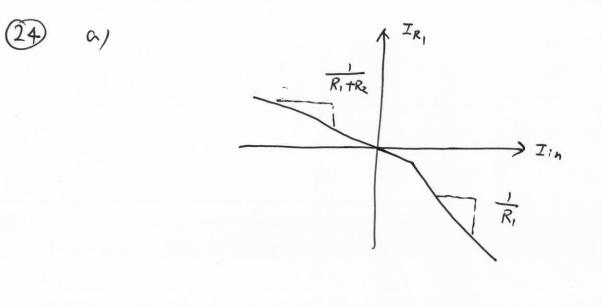


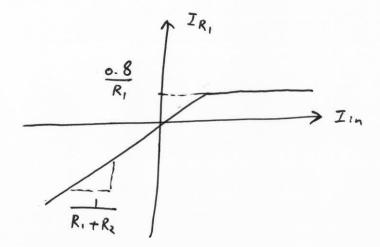






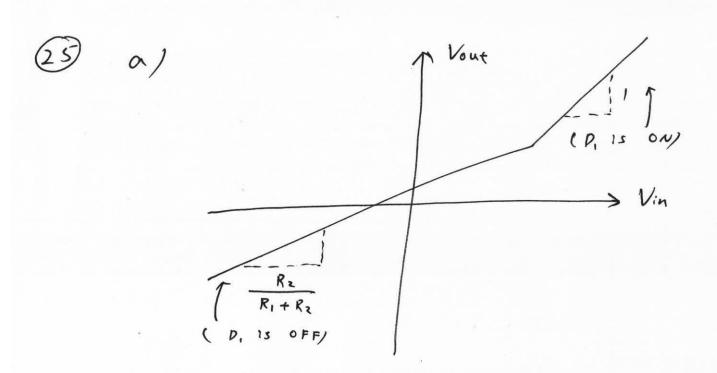


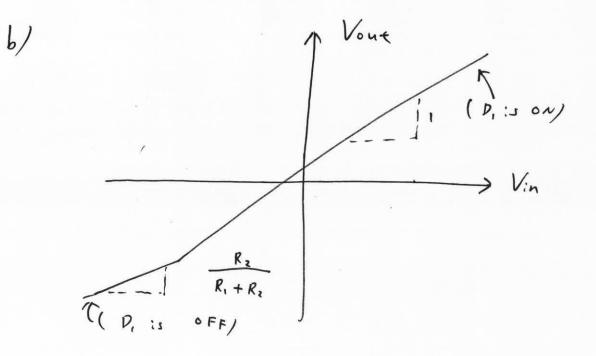


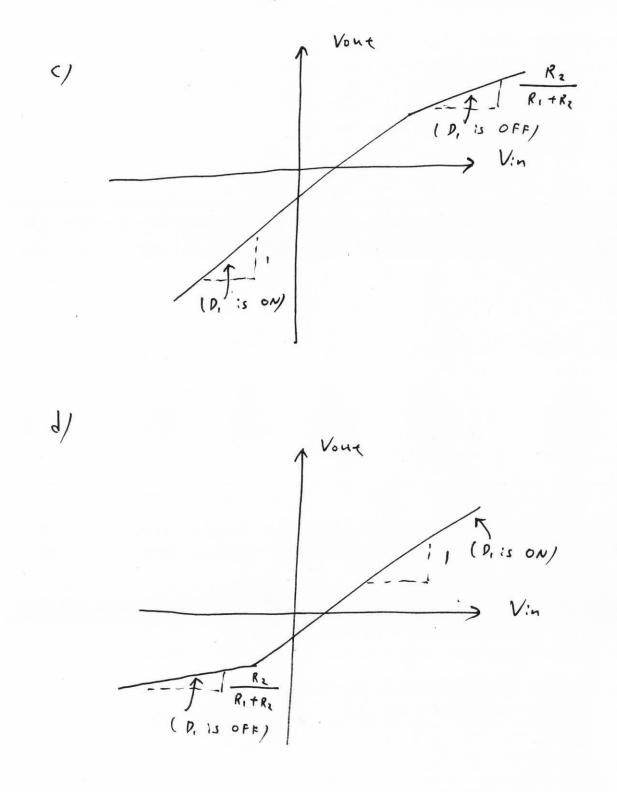


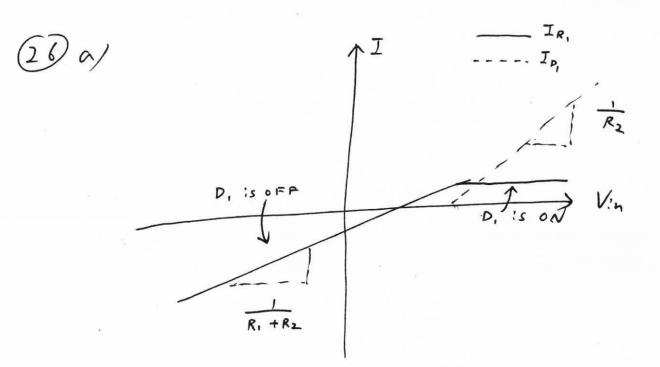
b/

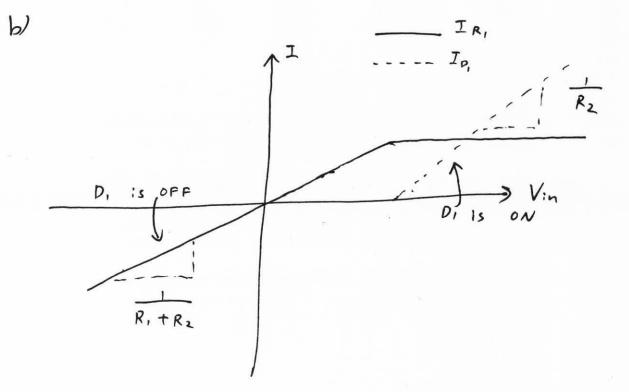
÷

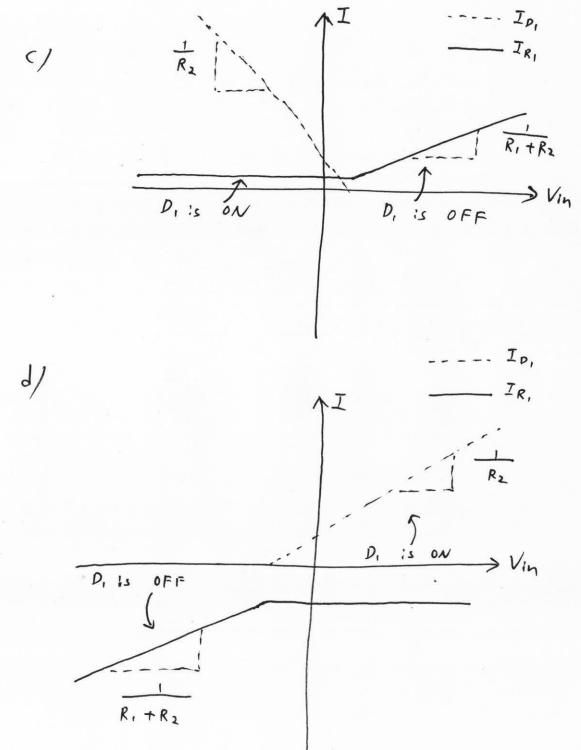


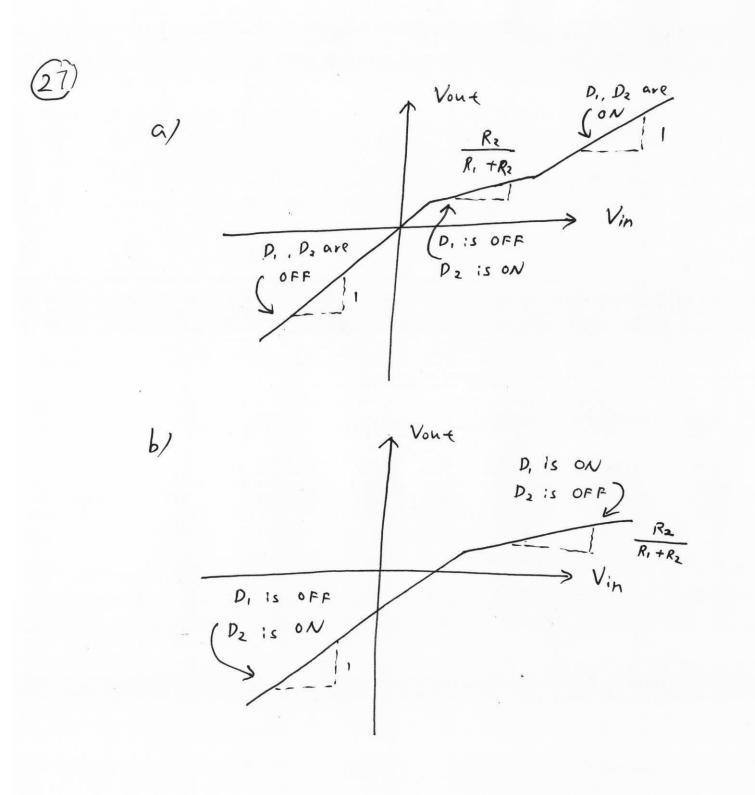


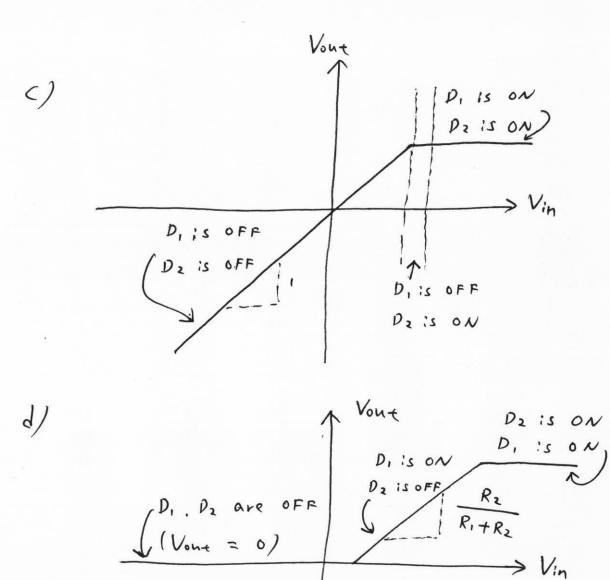


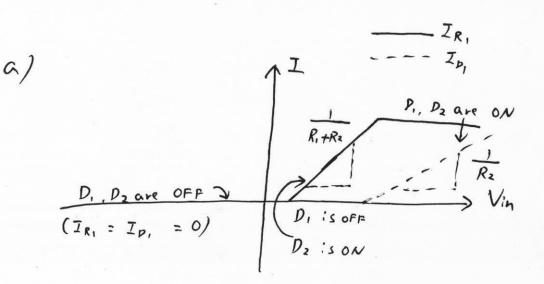


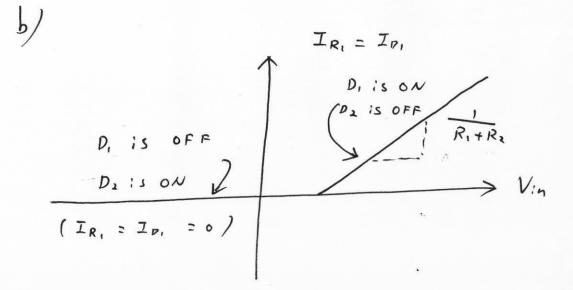


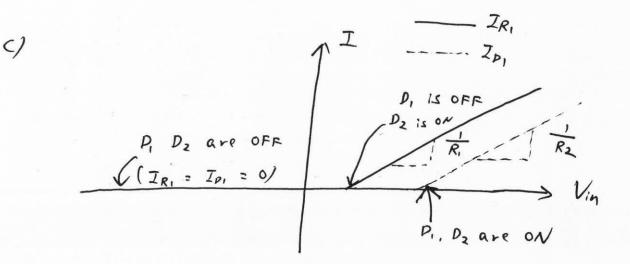


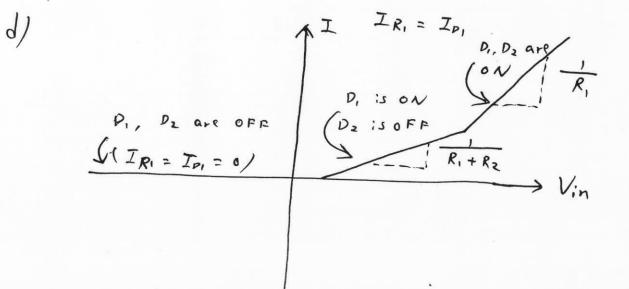


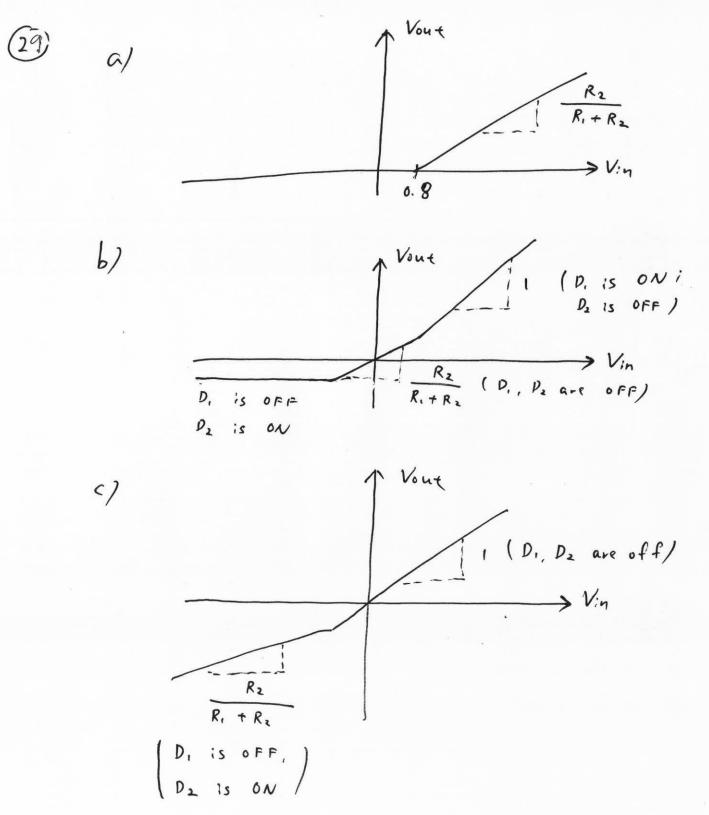


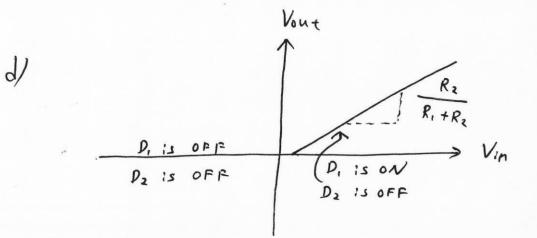


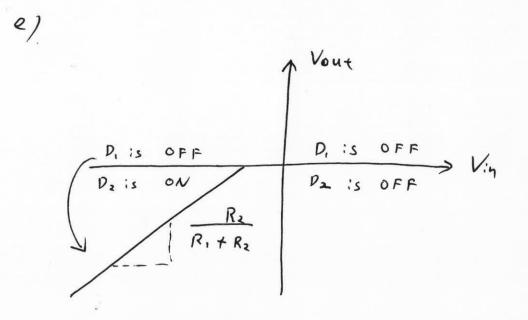


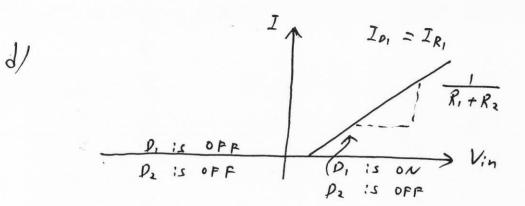


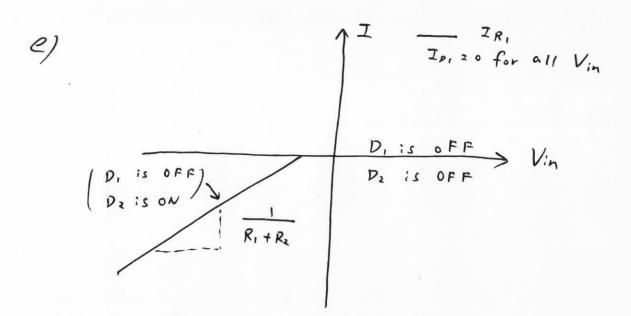


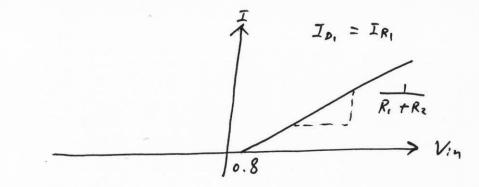




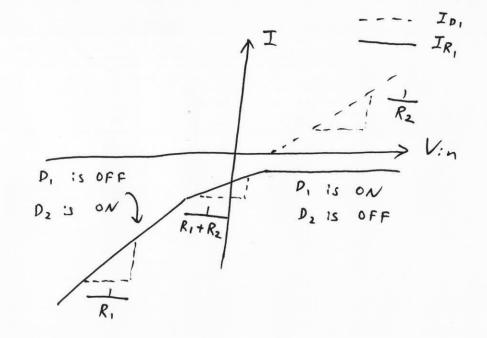


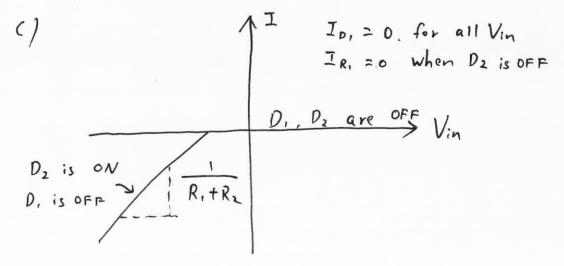






6/





L

$$\begin{array}{rcl}
(32) & a) & Vout &= i \times R_i \\
&= 0.1 \, \text{mA} \times 1 \, k \, \Omega \\
&= 0.1 \, V \end{array}$$

b/
$$r_{d_1} = r_{d_2} = \frac{26 \text{ mV}}{3 \text{ mA.}}$$
 (Eq. 3.58)
 $\approx 8.67 \Omega$.

$$V_{ont} = i \times (R_i + r_{d_2})$$

= 0.1 mA (1.00867 kR)

2 1.009 × 10-1 V

c)
$$V_{0n+} = i \times r_{d_2}$$

= 0.1 mA × 8.67 (from (b))
= 0.867 mV
d) $V_{0n+} = i \times (R_2 // r_{d_2})$
 $\approx i \times r_{d_2} (:: R_2 >> r_{d_2})$
= 0.867 mV

33 a/ $i_1 = i_{in}$ = 0.1 mA

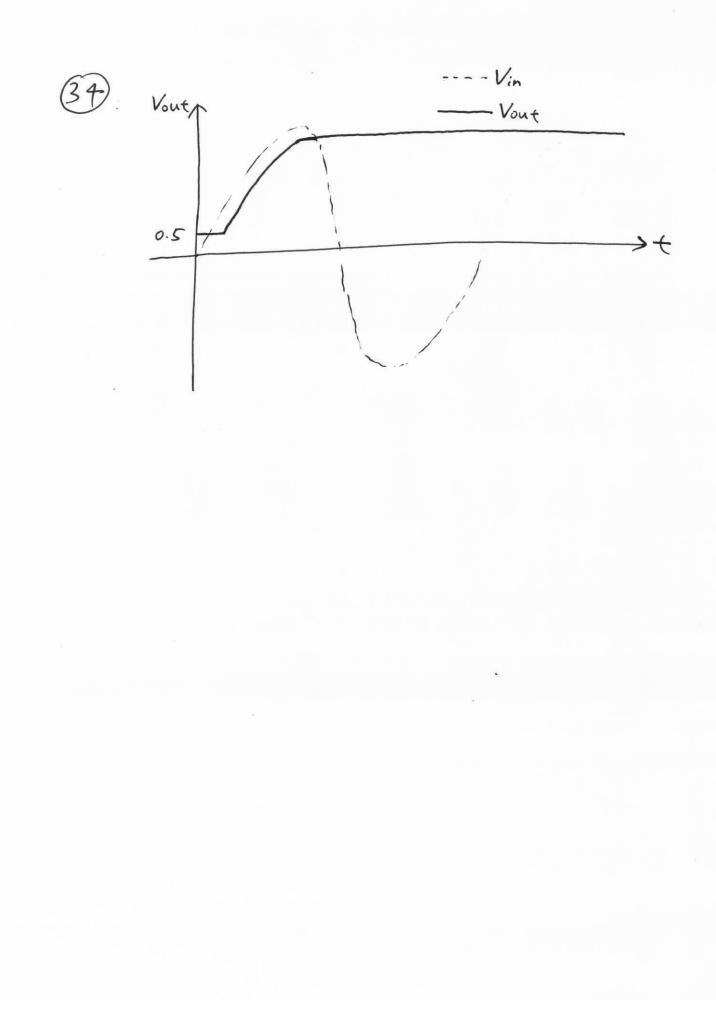
$$\frac{1}{r_1} = \frac{1}{r_1}$$
$$= 0.1 mF$$

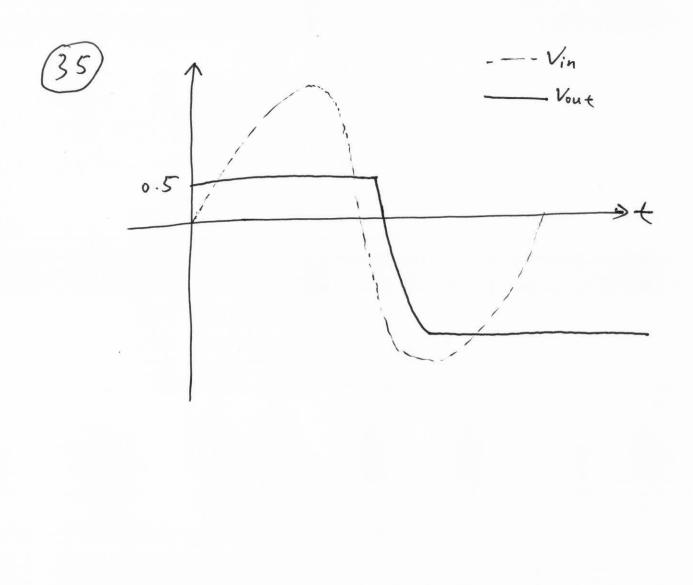
$$c/(i_r) = i_{in}$$

= 0.1 mA

d)
$$ir_1 = in_1$$

= 0.1 mA.





(36) From eq. (3.80),

Ripple amplitude, $V_R \approx \frac{V_P - V_{P,on}}{R_L \subset f_{in}}$

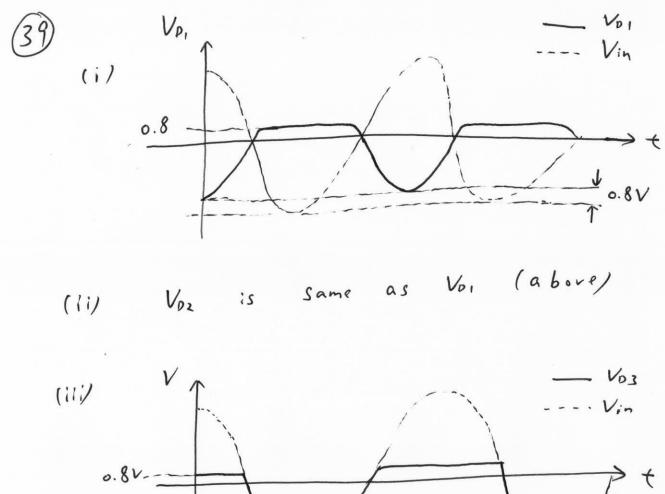
$$= \frac{3.5 - 0.8}{10 \ 1000 \times 10^{-6} \times 60}$$

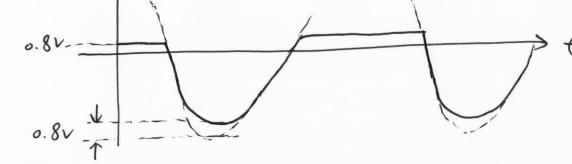
= 0.45V



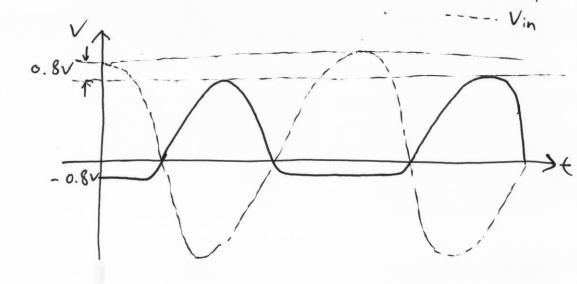
From Eq. (3.83), $V_{R} = \frac{I_{L}}{C f_{in}}$ $V_{R} \leq 300 \text{ mV}$ $\frac{I_{L}}{C f_{in}} \leq 300 \text{ mV}$ $i \leq F_{in} \leq 300 \text{ mV}$ $i \leq F_{in} \leq 300 \text{ mV}$ $i \leq C \geq \frac{I_{L}}{f_{in} \times 0.3}$ $C \geq \frac{0.5}{60 \times 0.3}$

i.e. C ≥ 0.278F









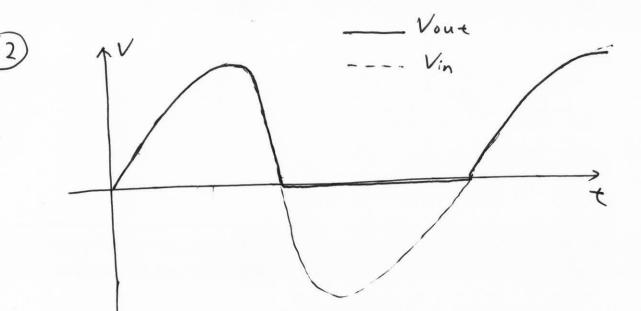
- V04

Pac! ton Cases. has no effect in the above two

(41) Using Eq. (3:94)

$$V_{R} = \frac{1}{2} \cdot \frac{V_{P} - 2 V_{P, oN}}{R_{L} c_{1} f_{in}}$$

= $\frac{1}{2} \cdot \frac{3 - 2 \times 0.8}{3 \circ \times 1000 \times 10^{-6} \times 60}$



- -With the two negative terminals shorted together, the sircuit behaves like a half-wave restifier.
- When Vin+>Vin-, D3 and D4 conjuct as usual. There will be an additional path that by passes D4, since Vin- and Vone-are shorted. But this additional path causes no change to the Vont waveform.
 When Vin->Vin+, both Vone + and Vone-track Vin-. Vone+ connects to Vin- through Pij Vone- connect to Vin- through the additional shorted path.
- Thus (Vone +) (Vone -) = 0, ie. Vone = 0



The circuit can

First, find rd:

 $Y_{d} = \frac{V_{T}}{I_{D}} \qquad (from eq. 3.60)$ $= \frac{26mV}{5mA}$ $= 5.2 \Omega$

Since $i_R = +1 mA$. $i_d = -1mA$.

: change in Vone,
i.e. Voue =
$$(-1mA)(3 \times 5.2)$$

= $-15.6 mV$

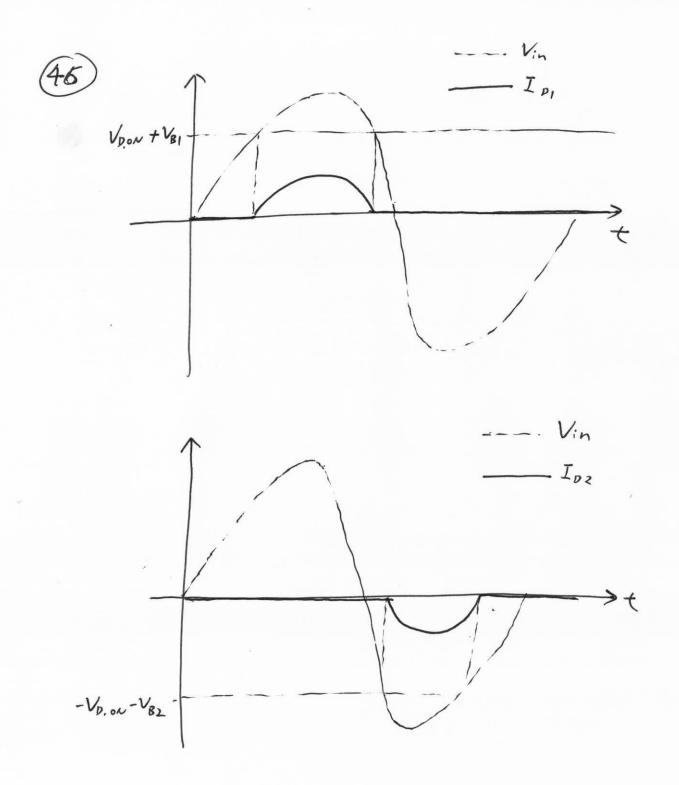
as !

) a) From Eq. (3.94),
the ripple amplitude,
$$V_R = \frac{1}{2} \cdot \frac{V_{P-2}V_{P,on}}{R_1C, f_{in}}$$

 $= \frac{1}{2} \cdot \frac{5 - 2 \times 0.8}{1000 \times 100 \times 10^{-6} \times 60}$
 $= 0.283 V$

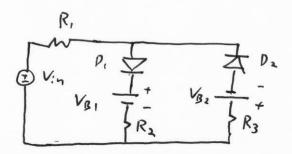
b) The ripple across the load, $V_R = i \times 3r_d$, where i is the change in current flowing through R, in series with the 3 dio des. $Y_d = \frac{V_T}{I_p}$ $\approx \frac{26mV}{5/R_1} = 5.2\Omega$ $i \approx \frac{V_R}{R_1 + 3r_d}$ = 0.279 mA $V_R = 0.279 \text{ mA}$

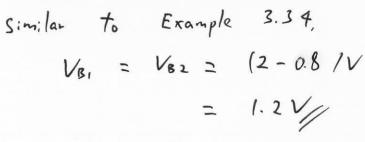
(45) With positive theshold =
$$+2.2V$$
,
 $V_{B1} = 2.2 - 0.8$
 $= +1.4V$
with negative three hold = $-1.9V$,
 $-V_{B2} = -1.9 + 0.8$
 $= -1.1V$.
 $V_{B2} = 1.1V$
To meet the maximum current criterion,
Since $I_{R_1} = I_{D_1}$ or I_{D_2} ,
 I_{D_1} or I_{D_2} is at max when
 I_{R_1} is at max.
 I_{R_1} is at max.
 I_{R_1} is at max.
 I_{R_1} is at max.
 $I_{R_1} \leq 2 -1.9$
 $= 3.1V$.
Since $I_{R_1} \leq 2 -1.9$
 $= 3.1V$.
 $Since I_{R_1} \leq 2 -1.9$
 $= 3.1V$.



(47)

The required circuit is:





To find Rz. For Vin > 2V, Vour has a slope of 0.5. This implies R2 = R, (R, and R2 form a volt. divider) Similarly, $R_3 = R$. Thus, set $R_1 = R_2 = R_3 = 1 k \Omega$. The resulting circuit is : IKR Vin E 1.2V Vont

(43) For
$$|Vin| < 4V$$
, the Vone -Vin characteristic
is similar to prob. (47).
To get Voltage limiting characteristic
for Vin >4V, and Vin < -4V,
we can shunt the circule used in prob(47)
with two antiparellel diodes as below:
 $Vin 1.2v + 1.$

Resulting circuit is:

